NSN 5961-01-036-5814

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-036-5814 **Inclosure Material:** Metal **Overall Length:** Between 3.475 inches and 3.525 inches **Terminal Length:** Between 0.730 inches and 0.760 inches **Overall Height:** 1.775 inches **Overall Width:** Between 2.975 inches and 3.025 inches **End Application:** An/tsq-73 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 190.0 breakdown voltage, dc **Current Rating Per Characteristic:** 200.00 amperes forward current, average preset and 100.00 amperes forward current, average pascal **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold **Test Data Document:** 18876-10284750 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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